## TAPERED LASER

GaAs Semiconductor Laser Diode



PRELIMINARY SPECIFICATION

### **Tapered Laser**

# General Product Information Product Application 780 nm Tapered Laser Spectroscopy C-Mount Package Metrology Raman Spectroscopy Raman Spectroscopy

EYP-TPL-0780-01000-3006-CMT03-0000

#### Absolute Maximum Ratings

	Symbol	Unit	min	typ	max
Storage Temperature	Ts	°C	-40		85
Operational Temperature at Case	T <sub>C</sub>	°C	0		50
Current	I <sub>F</sub>	А			2.8
Reverse Voltage	V <sub>R</sub>	V			0
Output Power	P <sub>opt</sub>	W			1.1

#### **Recommended Operational Conditions**

	Symbol	Unit	min	typ	max
Operational Temperature at Case	T <sub>C</sub>	°C	15		40
Forward Current	I <sub>F</sub>	А			2.5
Output Power	P <sub>opt</sub>	W			1.0

#### Characteristics at T<sub>amb</sub> 25 °C at Begin Of Life

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	$\lambda_{C}$	nm	775	780	785
Spectral Width (FWHM)	Δλ	nm		2	4
Temperature Coefficient of Wavelength	dλ / dT	nm / K		0.3	
Output Power @ $I_F = 2.5 A$	P <sub>opt</sub>	W	1.0		
Slope Efficiency	η	W/A	0.8	0.9	
Threshold Current	I <sub>th</sub>	А	0.4	0.6	0.8
Operational Current @ $P_{opt} = 1 W$	I <sub>F</sub>	А			2.5
Cavity Length	L	μm		2750	



#### non condensing

non condensing

Stress in excess of the Absolute Maximum Ratings can cause permanent damage to the device. Operation at the Absolute Maximum Rating for extended periods of time can adversely affect the device realibility and may lead to reduced operational life.

non condensing		

Measurement Conditions / Comments see images on page 4

total output measured with integrating sphere

eagleyard Photonics GmbH

Rudower Chaussee 29 (IGZ) 12490 Berlin GERMANY fon +49. 30. 6392 4520 fax +49. 30. 6392 4529 info@eagleyard.com www.eagleyard.com



## TAPERED LASER

GaAs Semiconductor Laser Diode



# PRELIMINARY SPECIFICATION

# Tapered Laser

# EYP-TPL-0780-01000-3006-CMT03-0000

#### Characteristics at T<sub>amb</sub> 25 °C at Begin Of Life

Parameter	Symbol	Unit	min	typ	max
Output Aperture (at front side)	d <sub>output</sub>	μm		190	
Astigmatism	А	μm		500	750
Divergence parallel (FWHM)	$\Theta_{  }$	0	12	15	18
Divergence perpendicular (FWHM)	$\Theta_{\perp}$	0		28	
Polarization				TM	

Measurement Conditions / Comments				
E field perpendicular to junction plane				

fon +49. 30. 6392 4520 fax +49. 30. 6392 4529 info@eagleyard.com www.eagleyard.com



## TAPERED LASER

GaAs Semiconductor Laser Diode

Version 0.90 24.01.2008 page: 3 from 4

# PRELIMINARY SPECIFICATION

**Tapered Laser** 

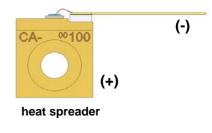
# EYP-TPL-0780-01000-3006-CMT03-0000

Package Dimensions					
	Symbol	Unit	min	typ	max
Emission Plane	I	mm	7.05	7.20	7.35
C-Mount Thickness	d	mm		2.75	

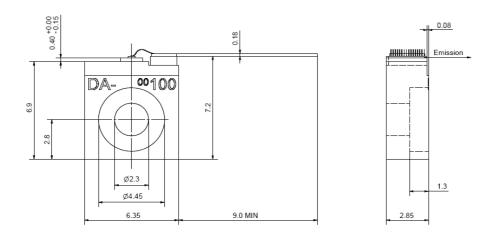
#### Package Pinout

Cathode (-)	Mounting Wire	
Cathode (-) Anode (+)	Housing	

# mounting wire



### Package Drawings

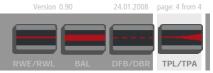


eagleyard Photonics GmbH

Rudower Chaussee 29 (IGZ) 12490 Berlin GERMANY fon +49. 30. 6392 4520 fax +49. 30. 6392 4529 info@eagleyard.com www.eagleyard.com



5,

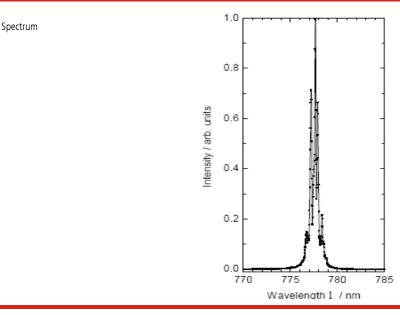


#### PRELIMINARY SPECIFICATION

**Tapered Laser** 

# EYP-TPL-0780-01000-3006-CMT03-0000

#### **Typical Measurement Results**



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

#### Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The TPL diode type is known to be sensitive against thermal stress. Operating at moderate temperatures on propper heat sinks will contribute to a long lifetime of the diode.

The laser emission from this diode is close to the invisible infrared region of the electromagnetic spectrum. Avoid direct and/or indirect exposure to the free running beam. Collimating the free running beam with optics as common in optical instruments will increase thread to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.





eagleyard Photonics GmbH

Rudower Chaussee 29 (IGZ) 12490 Berlin GERMANY fon +49. 30. 6392 4520 fax +49. 30. 6392 4529

info@eagleyard.com www.eagleyard.com

